

#### INCHANGE SEMICONDUCTOR

# isc N-Channel MOSFET Transistor

# **IXTP450P2**

#### • FEATURES

- With TO-220 packaging
- High speed switching
- · Low gate input resistance
- · Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

#### APPLICATIONS

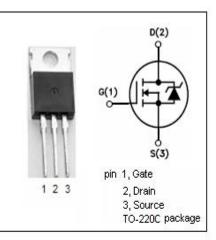
- Power supply
- Switching applications

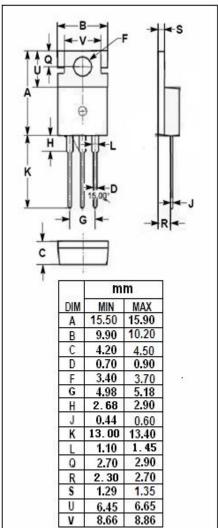
SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage	500	V				
V <sub>GSS</sub>	Gate-Source Voltage	±30	V				
ID	Drain Current-Continuous	16	A				
I <sub>DM</sub>	Drain Current-Single Pulsed	48	A				
PD	Total Dissipation	300	W				
Tj	Operating Junction Temperature	150	°C				
T <sub>stg</sub>	Storage Temperature	-55~150	°C				

#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.42	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	60	°C <b>/W</b>	

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#### isc website: www.iscsemi.cn

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#### ELECTRICAL CHARACTERISTICS

 $T_{\text{C}}\text{=}25^\circ\!\!\mathbb{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	500			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA	2.5		4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =8A			330	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±30V;V <sub>DS</sub> =0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 100V; V <sub>GS</sub> = 0V;Tj=25℃ V <sub>DS</sub> = 100V; V <sub>GS</sub> = 0V;Tj=125℃			5 25	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =16A, V <sub>GS</sub> = 0 V			1.3	V

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